

# **DDR3L SDRAM Data Sheet Addendum**

MT41K1G4 - 128 Meg x 4 x 8 banks MT41K512M8 - 64 Meg x 8 x 8 banks MT41K256M16 - 32 Meg x 16 x 8 banks

### **Description**

DDR3L SDRAM (1.35V) is a low voltage version of the DDR3 (1.5V) SDRAM. Refer to DDR3 (1.5V) SDRAM (Die Rev.: E) data sheet specifications when running in 1.5V compatible mode.

#### **Features**

- $V_{DD} = V_{DDO} = 1.35V (1.283 1.45V)$
- Backward compatible to  $V_{DD} = V_{DDQ} = 1.5V \pm 0.075V$ 
  - Supports DDR3L devices to be backward compatible in 1.5V applications
- Differential bidirectional data strobe
- 8*n*-bit prefetch architecture
- Differential clock inputs (CK, CK#)
- 8 internal banks
- Nominal and dynamic on-die termination (ODT) for data, strobe, and mask signals
- Programmable CAS (READ) latency (CL)
- Programmable posted CAS additive latency (AL)
- Programmable CAS (WRITE) latency (CWL)
- Fixed burst length (BL) of 8 and burst chop (BC) of 4 (via the mode register set [MRS])
- Selectable BC4 or BL8 on-the-fly (OTF)
- · Self refresh mode
- $T_C$  of 0°C to +95°C
  - 64ms, 8192-cycle refresh at 0°C to +85°C
  - 32ms at +85°C to +95°C

- Self refresh temperature (SRT)
- Automatic self refresh (ASR)
- Write leveling
- Multipurpose register
- Output driver calibration

Options	Marking
• Configuration	
- 1 Gig x 4	1G4
- 512 Meg x 8	512M8
- 256 Meg x 16	256M16
• FBGA package (Pb-free) – x4, x8	
<ul> <li>78-ball (8mm x 10.5mm) Rev. P</li> </ul>	DA
<ul> <li>FBGA package (Pb-free) – x16</li> </ul>	
<ul> <li>96-ball (8mm x 14mm) Rev. P</li> </ul>	TW
<ul> <li>Timing – cycle time</li> </ul>	
- 938ps @ CL = 14 (DDR3-2133)	-093
- 1.07ns @ CL = 13 (DDR3-1866)	-107
- 1.25ns @ CL = 11 (DDR3-1600)	-125
<ul> <li>Special Options</li> </ul>	
<ul> <li>Premium Lifecycle Product (PLP)</li> </ul>	X
<ul> <li>Operating temperature</li> </ul>	
- Commercial ( $0^{\circ}$ C $\leq$ T <sub>C</sub> $\leq$ +95 $^{\circ}$ C)	None
- Industrial ( $-40^{\circ}$ C $\leq$ T <sub>C</sub> $\leq$ +95 $^{\circ}$ C)	IT
<ul> <li>Revision</li> </ul>	P

#### **Table 1: Key Timing Parameters**

	Speed Grade	Data Rate (MT/s)	Target <sup>t</sup> RCD- <sup>t</sup> RP-CL	<sup>t</sup> RCD (ns)	<sup>t</sup> RP (ns)	CL (ns)
	-093 <sup>1, 2</sup>	2133	14-14-14	13.09	13.09	13.09
ĺ	-107 <sup>1</sup>	1866	13-13-13	13.91	13.91	13.91
	-125	1600	11-11-11	13.75	13.75	13.75

Notes: 1. Backward compatible to 1600, CL = 11 (-125).

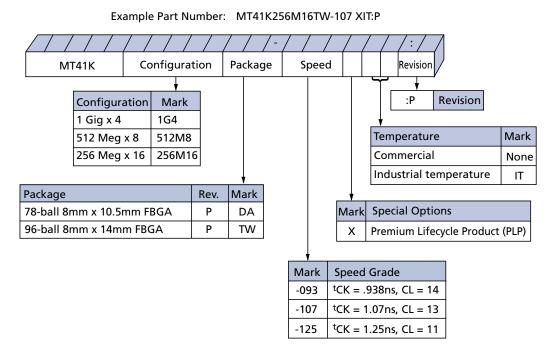
2. Backward compatible to 1866, CL = 13 (-107).



**Table 2: Addressing** 

Parameter	1 Gig x 4	512 Meg x 8	256 Meg x 16	
Configuration	128 Meg x 4 x 8 banks 64 Meg x 8 x 8 banks		32 Meg x 16 x 8 banks	
Refresh count	8K	8K 8K		
Row address	64K (A[15:0])	64K (A[15:0])	32K (A[14:0])	
Bank address	8 (BA[2:0])	8 (BA[2:0])	8 (BA[2:0])	
Column address	2K (A[11, 9:0])	1K (A[9:0])	1K (A[9:0])	
Page size	1KB	1KB	2KB	

**Figure 1: DDR3L Part Numbers** 



Note: 1. Not all options listed can be combined to define an offered product. Use the part catalog search on http://www.micron.com for available offerings.

## **FBGA Part Marking Decoder**

Due to space limitations, FBGA-packaged components have an abbreviated part marking that is different from the part number. For a quick conversion of an FBGA code, see the FBGA Part Marking Decoder on Micron's Web site: http://www.micron.com.





### **Revision History**

Rev. A - 02/16

• Initial release based on the 4Gb x4, x8, x16 DDR3L SDRAM, Rev. N 12/15 data sheet

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This data sheet contains minimum and maximum limits specified over the power supply and temperature range set forth herein. Although considered final, these specifications are subject to change, as further product development and data characterization sometimes occur.